

## Recent Progress on Ga<sub>2</sub>O<sub>3</sub> Sensors and GaN Electronics

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**Abstract:** In this presentation we will discuss our recent work on Ga<sub>2</sub>O<sub>3</sub>-based sensors and GaN radiation-tolerant circuits. In the first part of the presentation, we will discuss the design, demonstration, and characteristics of vertical Ga<sub>2</sub>O<sub>3</sub>-based Schottky and heterojunction diodes, and designs for future Ga<sub>2</sub>O<sub>3</sub> sensors that could enable lower dark current and higher sensitivity. In the second part of the presentation we will discuss our efforts to develop a broadly accessible platform for GaN-based logic circuits based on enhancement-depletion mode transistor circuit designs.